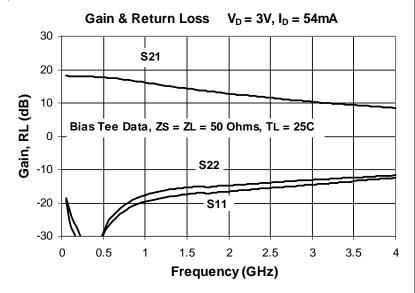


Sirenza Microdevices⁷ SGC-4363Z is a high performance SiGe HBT MMIC amplifier utilizing a Darlington configuration with a patented active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 3V supply, the SGC-4363Z does not require a dropping resistor as compared to typical Darlington amplifiers. The SGC-4363Z is designed for high linearity 3V gain block applications that require small size and minimal external components. It is internally matched to 50 ohms.



SGC-4363Z

50-4000 MHz Active Bias Silicon Germanium Cascadable Gain Block





Product Features

- Single Fixed 3V Supply
- No Dropping Resistor Required
- Patented Self-Bias Circuitry
- P1dB = 12.4 dBm at 1950 MHz
- OIP3 = 26.5 dBm at 1950 MHz
- Robust 1000V ESD, Class 1C HBM

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS, WCDMA
- IF Amplifier
- Wireless Data, Satellite

Symbol	Parameters	Units	Frequency	Min.	Тур.	Max.
			850 MHz	850 MHz 15.6 1	17.1	18.6
G	Small Signal Gain	dB	1950 MHz	11.2	12.7	14.2
			2400 MHz		11.8	
	Output Power at 1dB Compression	dBm	850 MHz		13.3	
P _{1dB}			1950 MHz	11.4	12.4	
			2400 MHz		11.8	
			850 MHz		28.5	
OIP ₃	Output Third Order Intercept Point	dBm	1950 MHz	24.5	26.5	
			2400 MHz		25.5	
IRL	Input Return Loss	dB	1950 MHz	9.5	13.5	
ORL	Output Return Loss	dB	1950 MHz	8.5	12.5	
NF	Noise Figure	dB	1930 MHz		4.0	5.0
V _D	Device Operating Voltage	V			3	
Ι _D	Device Operating Current	mA		48	54	60
Rth, j-l	Thermal Resistance (junction to lead)	°C/W			180	
Test Conditions: $V_D = 3.0V$ $I_D = 54mA$ $T_L = 25^{\circ}C$ Bias Tee Data $Z_S = Z_L = 5$			OIP ₃ Tone Spa	Z		
		50 Ohms	Pout per tone			

The information provided herein is believed to be reliable at press time. Sirenza Microdevices assumes no responsibility for inaccuracies or omissions. Sirenza Microdevices assumes no responsibility for the use of this information, and all such information shall be entirely at the user's own risk. Prices and specifications are subject to change without notice. No patent rights or licenses to any of the circuits described herein are implied or granted to any third party. Sirenza Microdevices does not authorize or warrant any Sirenza Microdevices product for use in life-support devices and/or systems. Copyright 2005 Sirenza Microdevices, Inc.. All worldwide rights reserved.

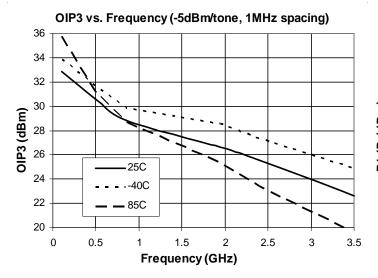
303 S. Technology Ct. Broomfield, CO 80021

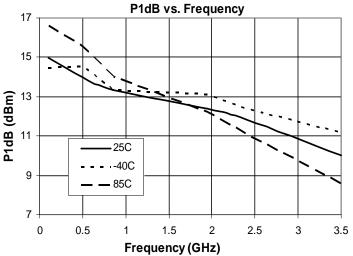
EDS-104977 Rev C



Symbol	Parameter	Unit	Frequency (MHz)					
Symbol		onin	100	500	850	1950	2400	3500
G	Small Signal Gain	dB	18.0	17.7	17.1	12.7	11.8	9.4
OIP ₃	Output Third Order Intercept Point	dBm	33.5	30.5	28.5	26.5	25.5	22.5
P_{1dB}	Output Power at 1dB Compression	dBm	14.9	14.0	13.3	12.4	11.8	10.0
IRL	Input Return Loss	dB	26.5	21.5	18.5	13.5	14.0	12.0
ORL	Output Return Loss	dB	25.0	21.0	17.5	12.5	12.0	11.0
S ₁₂	Reverse Isolation	dB	20.0	21.0	21.5	20.0	19.5	19.0
NF	Noise Figure	dB	2.9	3.1	3.5	4.0	4.2	5.1

Typical Performance with Bias Tee, $V_{D} = 3V$, $I_{D} = 54mA$





Caution: ESD sensitive

Appropriate precautions in handling, packaging

and testing devices must be observed.

Absolute Maximu	m Ratings	Reliability & Qualification Information			
Parameter	Absolute Limit	Parameter	Rating		
Max Device Current (I _{CE})	110 mA	ESD Rating - Human Body Model (HBM)	Class 1C MSL 1		
Max Device Voltage (V _{CE})	4.5 V	Moisture Sensitivity Level			
Max. RF Input Power* (See Note)	+18 dBm	-			
Max. Junction Temp. (T _J)	+150°C	This product qualification report can be downloaded at			
Operating Temp. Range (T _L)	-40°C to +85°C	www.sirenza.com			
Max, Storage Temp,	+150°C				

*Note: Load condition, Z_L = 50 Ohms

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression: $I_DV_D < (T_J - T_L) / R_{TH}$, j-l $T_L=T_{LEAD}$

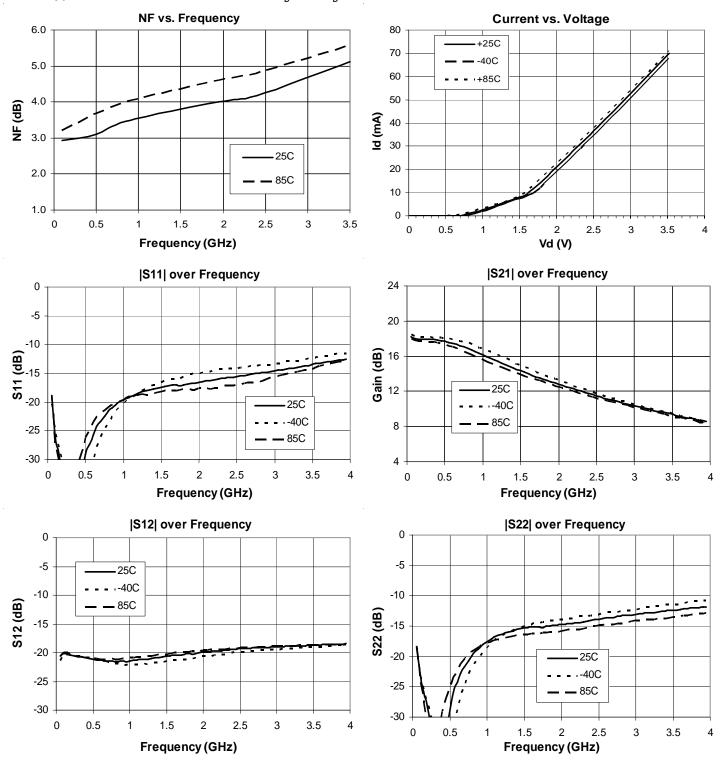
303 S. Technology Ct. Broomfield, CO 80021 Phone: (800) SMI-MMIC

http://www.sirenza.com EDS-104977 Rev C



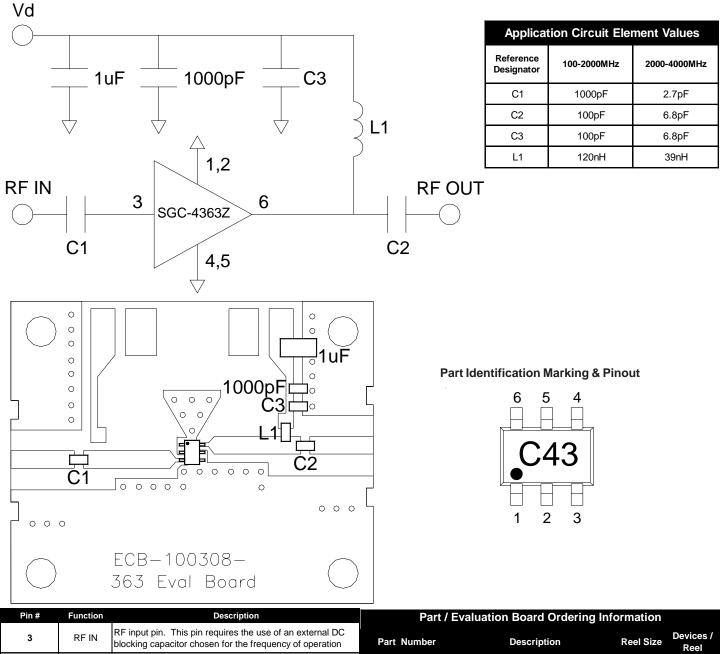
SGC-4363Z 0.05-4.0 GHz Cascadeable MMIC Amplifier

Typical Performance with Bias Tee, $V_D = 3V$, $I_D = 54mA$



303 S. Technology Ct. Broomfield, CO 80021

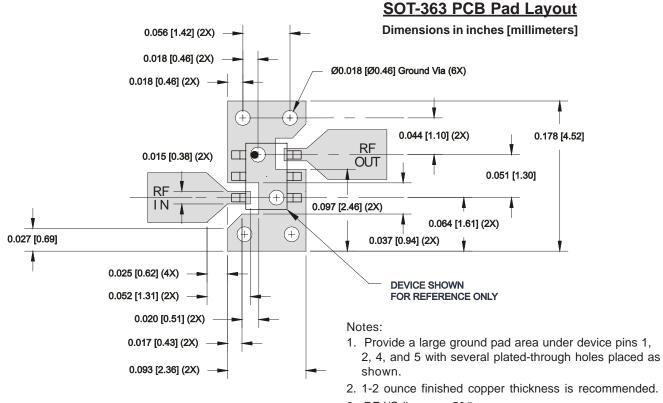




3		blocking capacitor chosen for the frequency of operation	Part Number	Description	Reel Size	Devices / Reel
1,2,4,5		Connection to ground. Use via holes as close to the device ground leads as possible to reduce ground inductance and	SGC-4363Z	Lead Free, RoHs Compliant	7"	3000
1,2,4,5		achieve optimum RF performance	SGC-4363Z-EVB1	100-2000 MHz Evaluation Board	N/A	N/A
		RF output and bias pin. This pin requires the use of an	SGC-4363Z-EVB2	2000-4000 MHz Evaluation Board	N/A	N/A
6 DC	DC BIAS operation.	external DC blocking capacitor chosen for the frequency of operation.				



SGC-4363Z 0.05-4.0 GHz Cascadeable MMIC Amplifier



3. RF I/O lines are 50Ω

SOT-363 Nominal Package Dimensions

Dimensions in inches [millimeters] A link to the SOT-363 package outline drawing with full dimensions and tolerances may be found on the product web page at www.sirenza.com.

